For partial switching PFC
Integrated IGBT and Diode Bridge Rectifier

SLA5222

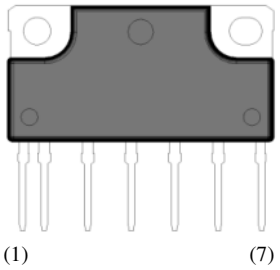
Features

- SLA5222 incorporates IGBT and diodes for bridge rectifier of partial switching PFC, and achieves board space reduction.
- Low Saturation Voltage IGBT
- Low V_F Diode Bridge Rectifier
- Clip Lead is adopted for inner lead
  -Low Inductance
  -Low Resistance
  -High Power Dissipation
  -Smoke generation and explosion are less likely to occur in case of destruction

- V_{CE} ---------- 600 V
- I_C----------30 A (T_C = 100 °C)
- $V_{CE(sat)}$----------1.3 V typ.
- t_f ---------- 170 ns typ.

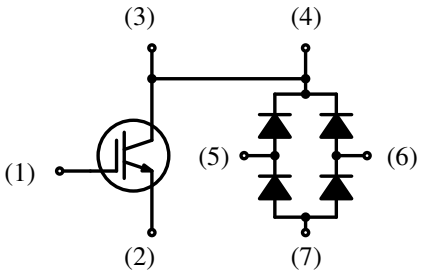
Package

SLA



Not to scale

Equivalent circuit



Applications

For partial switching PFC

- Air conditioner
- Other SMPS

Absolute Maximum Ratings

- Unless otherwise specified, T_A = 25 °C

Parameter	Symbol	Test conditions	Rating	Unit
Collector to Emitter Voltage	V_{CES}		600	V
Gate to Emitter Voltage	V_{GE}		± 30	V
Continuous Collector Current	$I_{C(DC)}$	T_C = 25 °C	30	A
Pulsed Collector Current	$I_{C\ (PULSE)}$ *1	PW ≤ 1ms Duty cycle ≤ 1 %	100	A
Maximum Collector to Emitter dv/dt	dv/dt *2	T_C ≤ 125 °C Refer to Figure 1	5	V/ns
Diode Peak Reverse Voltage	V_{RM}		600	V
Diode Forward Current	I_F		25	A
Diode Peak Surge Forward Current	I_{FSM} *3	PW ≤ 10ms, Half sinewave, 1 shot	200	A
Diode I^2t Limiting Value	I^2t *4	1 ms ≤ PW ≤ 10 ms	200	A^2s
Maximum Allowable Power Dissipation	P_T *5	No. Fin. All Element Operation	5	W
		All Element Operation	92	W
Isolation Voltage	V_{ISO}	Between fin and all pins	1500	Vrms
Operating Junction Temperature	T_J		150	°C
Storage Temperature Range	T_{stg}		− 40 to 150	°C

Thermal Characteristics

• Unless otherwise specified, T_A = 25 °C

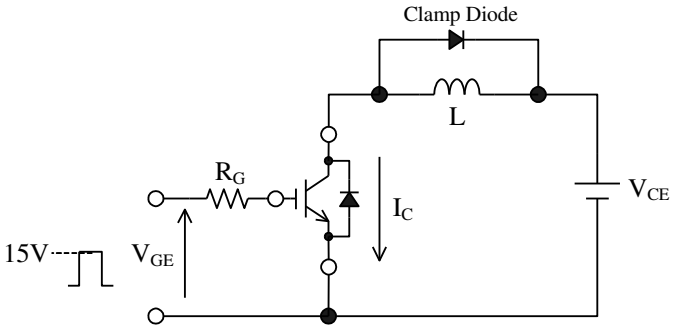
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Thermal Resistance (Junction to Ambient)	θ_{j-A}	All Element Operation	−	−	25	°C/W
Thermal Resistance (Junction to Case)	θ_{j-C}	All Element Operation	−	−	1.36	°C/W
Thermal Resistance (Junction to Case)	θ_{j-C} IGBT	IGBT 1 Element Operation	−	−	3.91	°C/W
Thermal Resistance (Junction to Case)	θ_{j-C} Di	Diode 1 Element Operation	−	−	8.33	°C/W

Electrical Characteristics

• Unless otherwise specified, T_A = 25 °C

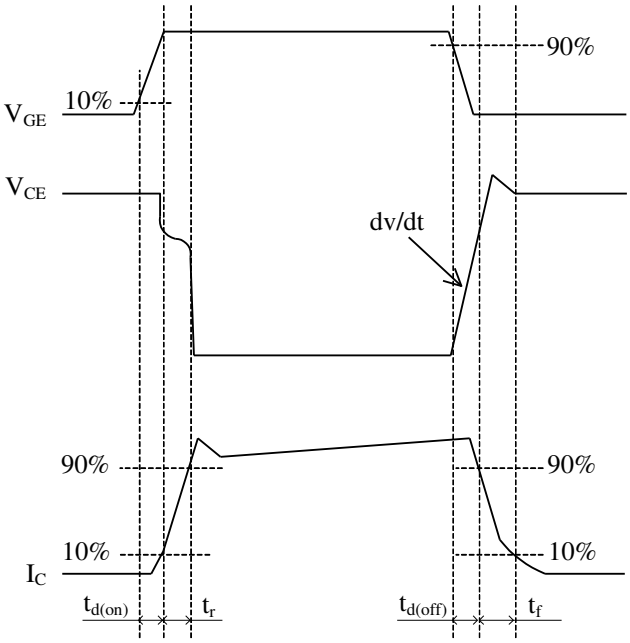
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
IGBT						
Collector to Emitter Breakdown Voltage	$V_{(BR)CES}$	I_C = 100 μA, V_{GE} = 0 V	600	−	−	V
Collector to Emitter Leakage Current	I_{CES}	V_{CE} = 600 V, V_{GE} = 0 V	−	−	100	μA
Gate to Emitter Leakage Current	I_{GES}	V_{GE} = ± 30 V	−	−	± 500	nA
Gate Threshold Voltage	$V_{GE(TH)}$	V_{CE} = 10 V, I_C = 1 mA	3	−	6	V
Gate Threshold Voltage Temperature Coefficient	$\Delta V_{GE(TH)}$	V_{CE} = 10V, I_D = 1 mA	−	8.5	−	mV/°C
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	V_{GE} = 15 V, I_C = 30 A	−	1.3	1.7	V
		V_{GE} = 15 V, I_C = 50 A	−	1.6	−	V
Input Capacitance	C_{ies}	V_{CE} = 20 V V_{GE} = 0 V f = 1.0 MHz	−	2500	−	pF
Output Capacitance	C_{oes}		−	150	−	
Reverse Transfer Capacitance	C_{res}		−	80	−	
Total Gate Charge	Q_g	V_{CE} = 300 V I_C = 30 A V_{GE} = 15 V	−	65	−	nC
Gate to Emitter Charge	Q_{ge}		−	20	−	
Gate to Collector Charge	Q_{gc}		−	20	−	
Turn-On Delay Time	$t_{d(on)}$	T_C = 25 °C Refer to Figure 1	−	70	−	ns
Rise Time	t_r		−	70	−	
Turn-Off Delay Time	$t_{d(off)}$		−	280	−	
Fall Time	t_f		−	170	−	
Turn-On Delay Time	$t_{d(on)}$	T_C = 125 °C Refer to Figure 1	−	70	−	ns
Rise Time	t_r		−	75	−	
Turn-Off Delay Time	$t_{d(off)}$		−	320	−	
Fall Time	t_f		−	300	−	
Diode						
Forward Voltage Drop	V_F	I_F = 12.5 A	−	−	1.1	V
Reverse Leakage Current	I_R	V_R = 600 V	−	−	50	μA

Test Circuits and Waveforms



Test conditions
V_{CE} = 300 V
I_C = 50 A
V_{GE} = 15 V
R_G = 39 Ω
L= 100 μH

(a) Test Circuit

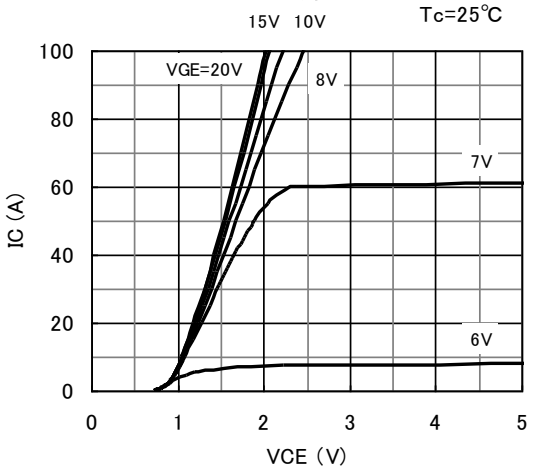


(b) Waveform

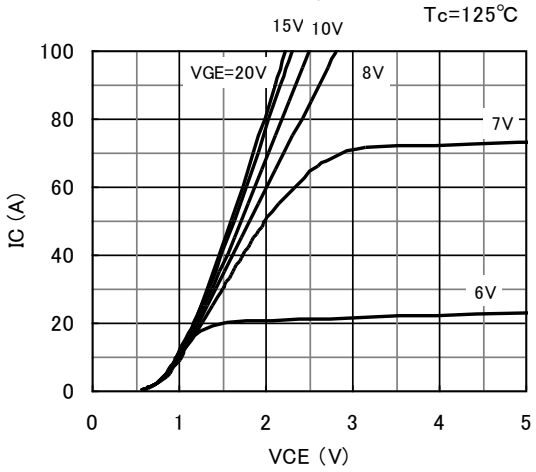
Figure 1 Test Circuits and waveforms of dv/dt and Switching Time

Performance Curves

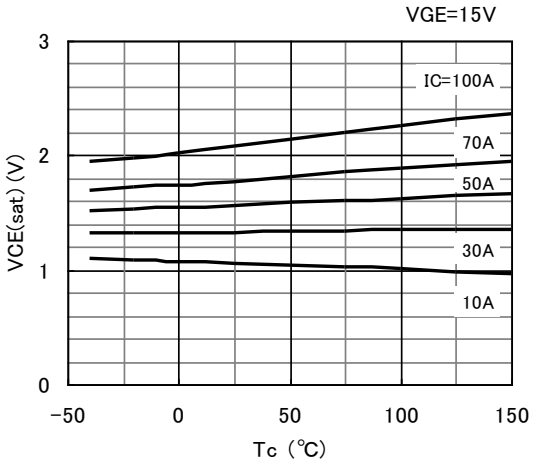
IC – VCE (typical)



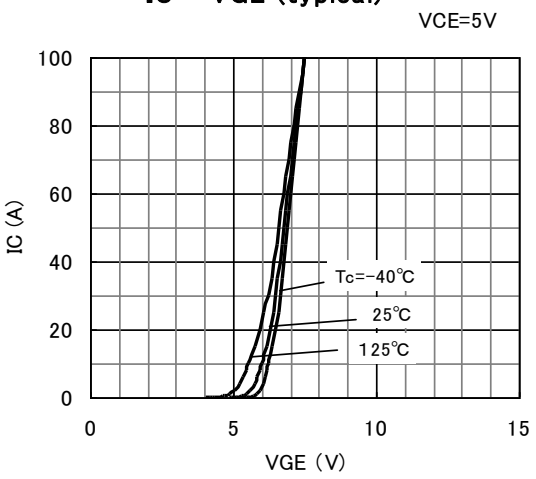
IC – VCE (typical)



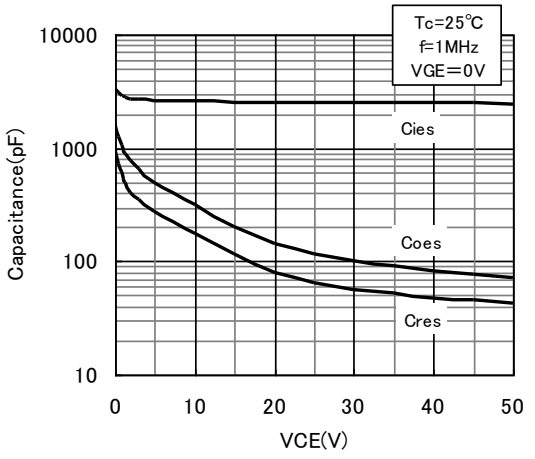
VCE(sat) – Tc (typical)



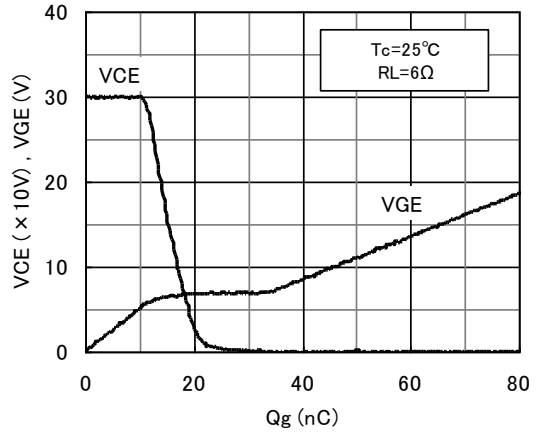
IC – VGE (typical)



Capa – VCE (typical)

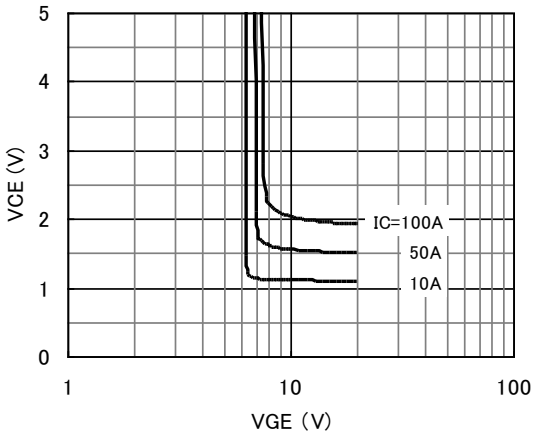


VCE,VGE – Qg (typical)



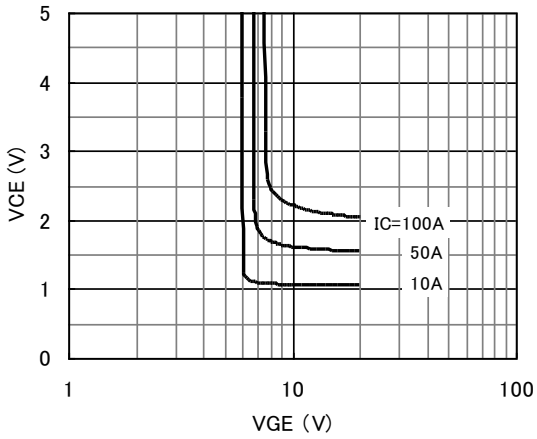
VCE – VGE (typical)

Tc=−40℃



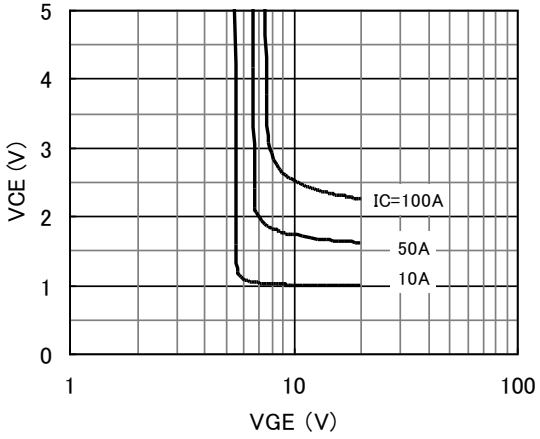
VCE – VGE (typical)

Tc=25℃



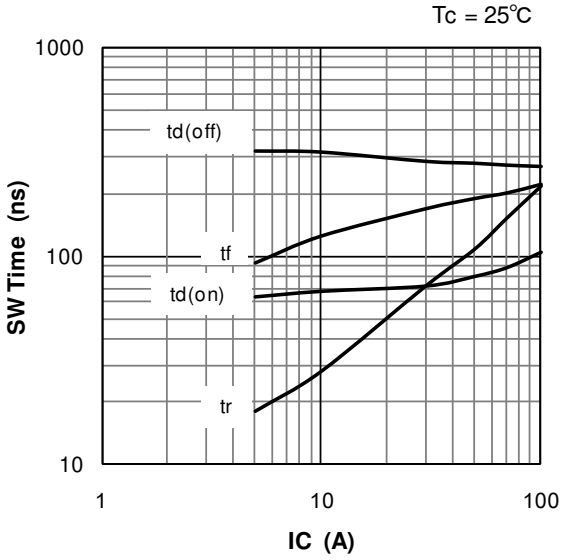
VCE – VGE (typical)

Tc=125℃



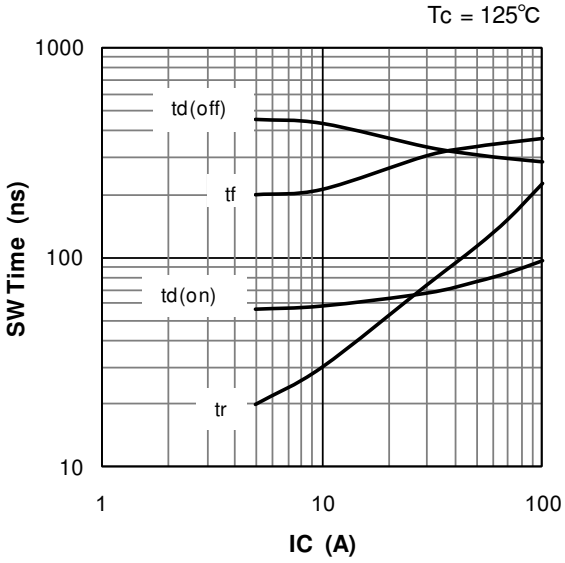
SW Time - IC (typical)

Tc = 25℃

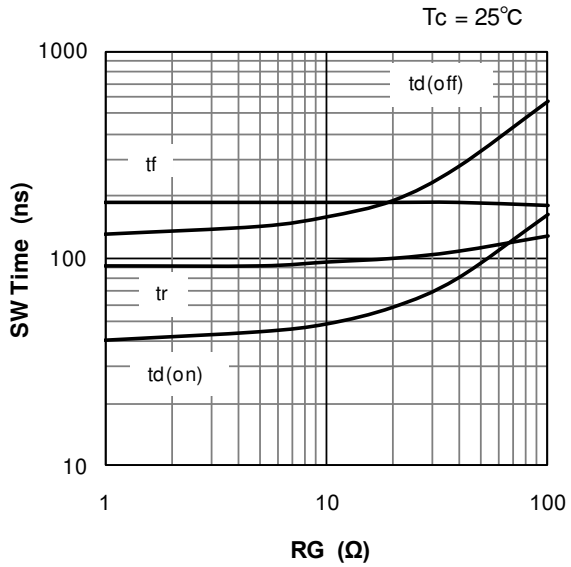


SW Time - IC (typical)

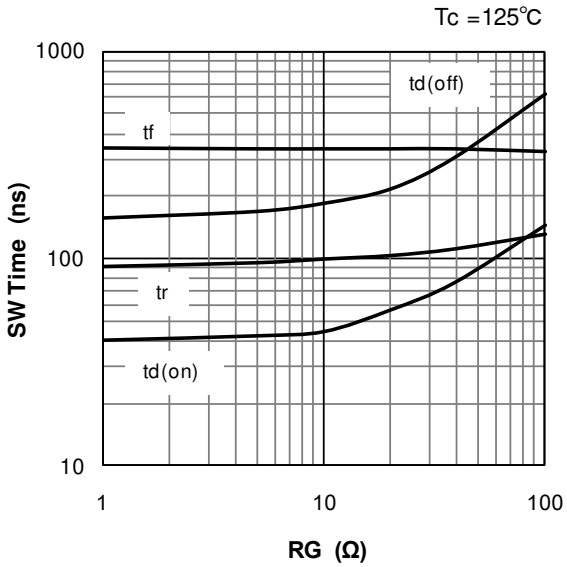
Tc = 125℃



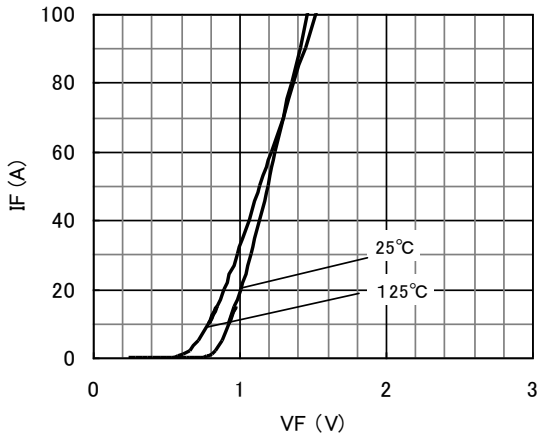
SW Time - RG (typical)



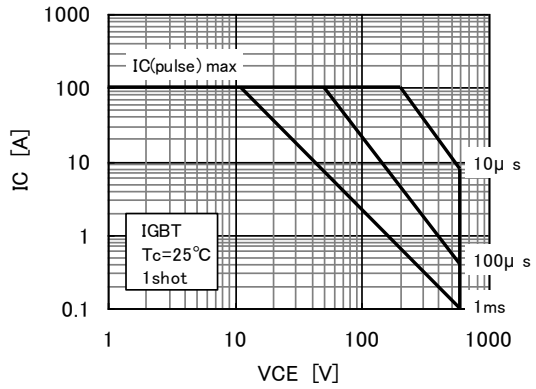
SW Time - RG (typical)



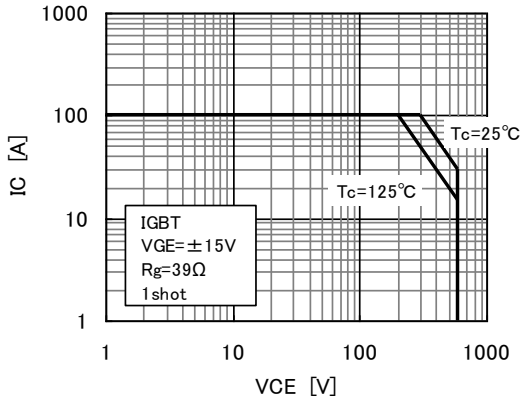
IF – VF (typical)



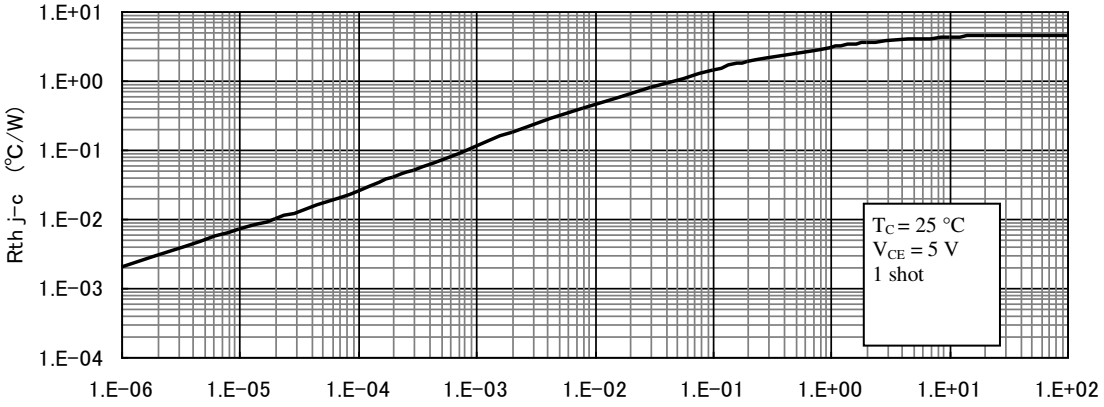
SAFE OPERATING AREA



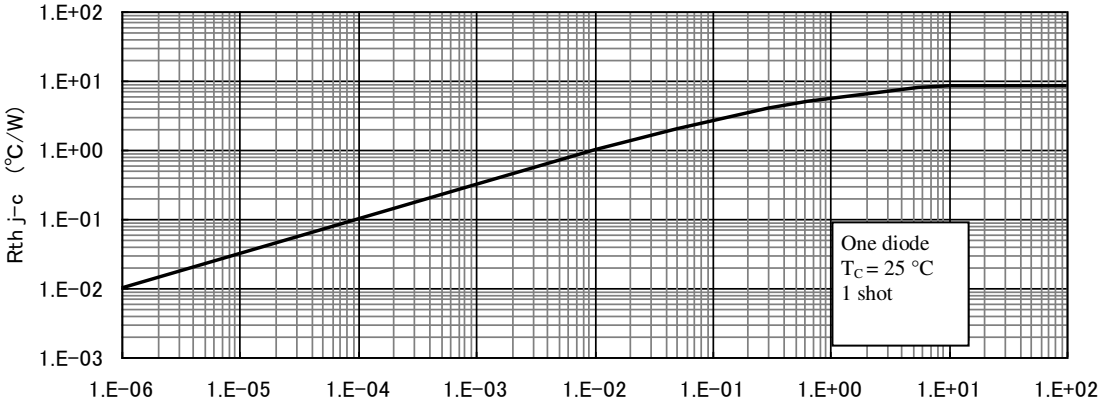
Reverse Bias ASO



Transient Thermal Resistance of IGBT (pulse width)

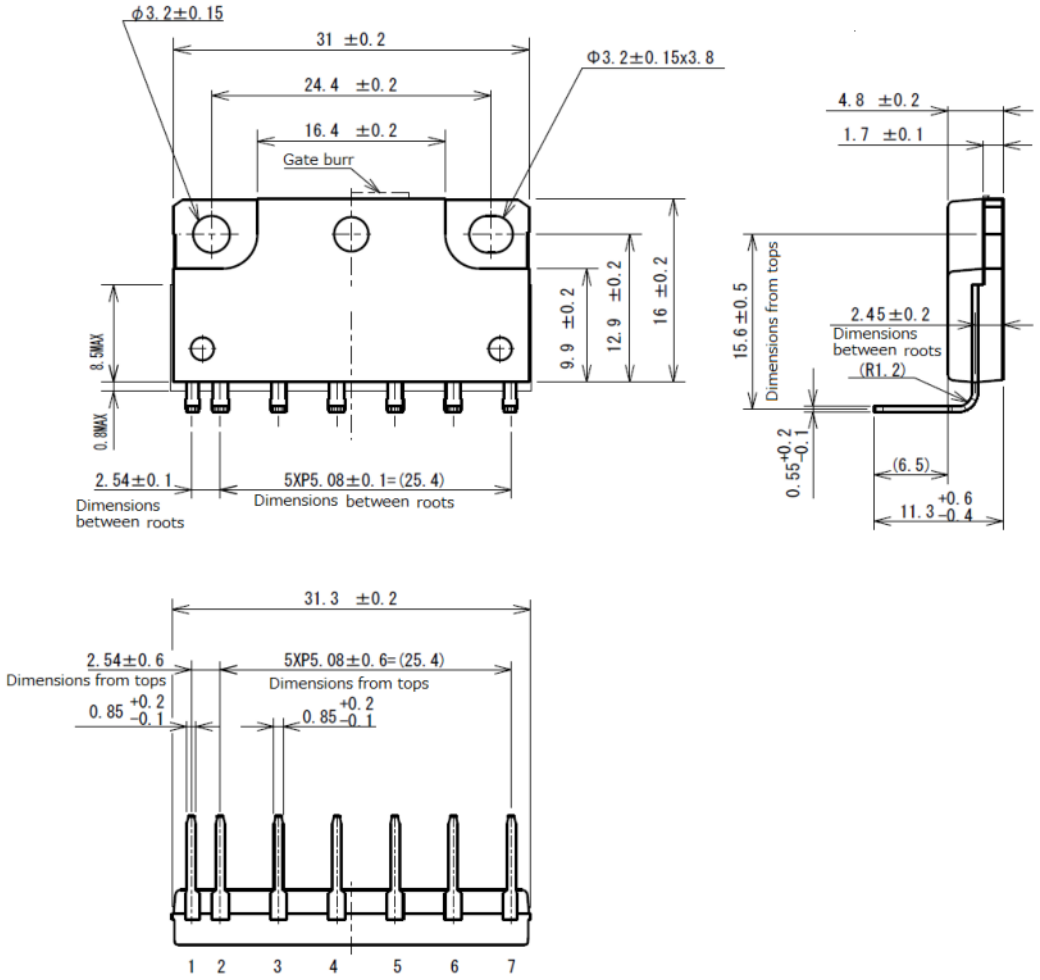


Transient Thermal Resistance of one diode (pulse width)



Package Outline

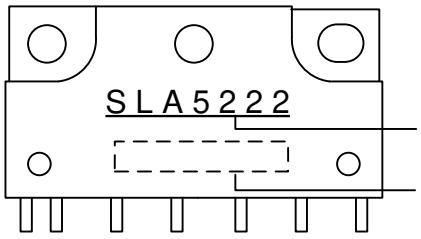
SLA (LF No. 821)



NOTES:

1) Dimension is in millimeters
2) Pb-free. Device composition compliant with the RoHS directive

Marking Diagram



Part Number

Lot Number

Y is the Last digit of year (0 to 9)
M is the Month (1 to 9, O ,N or D)
DD is the Date (two digit of 01 to 31)

OPERATING PRECAUTIONS

In the case that you use Sanken products or design your products by using Sanken products, the reliability largely depends on the degree of derating to be made to the rated values. Derating may be interpreted as a case that an operation range is set by derating the load from each rated value or surge voltage or noise is considered for derating in order to assure or improve the reliability. In general, derating factors include electric stresses such as electric voltage, electric current, electric power etc., environmental stresses such as ambient temperature, humidity etc. and thermal stress caused due to self-heating of semiconductor products. For these stresses, instantaneous values, maximum values and minimum values must be taken into consideration. In addition, it should be noted that since power devices or IC's including power devices have large self-heating value, the degree of derating of junction temperature affects the reliability significantly.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5 to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of the products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between the product pins, and wrong connections. Ensure all test parameters are within the ratings specified by Sanken for the products.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting the products on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce excess stress.
- Volatile-type silicone greases may crack after long periods of time, resulting in reduced heat radiation effect. Silicone greases with low consistency (hard grease) may cause cracks in the mold resin when screwing the products to a heatsink.
  Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Type	Suppliers
G746	Shin-Etsu Chemical Co., Ltd.
YG6260	Momentive Performance Materials Inc.
SC102	Dow Corning Toray Co., Ltd.

Cautions for Mounting to a Heatsink

- When the flatness around the screw hole is insufficient, such as when mounting the products to a heatsink that has an extruded (burred) screw hole, the products can be damaged, even with a lower than recommended screw torque. For mounting the products, the mounting surface flatness should be 0.05mm or less.
- Please select suitable screws for the product shape. Do not use a flat-head machine screw because of the stress to the products. Self-tapping screws are not recommended. When using self-tapping screws, the screw may enter the hole diagonally, not vertically, depending on the conditions of hole before threading or the work situation. That may stress the products and may cause failures.
- Recommended screw torque:

Package	Recommended Screw Torque
TO-220, TO-220F	0.490 to 0.686 N・m (5 to 7 kgf・cm)
TO-3P, TO-3PF, TO-247	0.686 to 0.882 N・m (7 to 9 kgf・cm)
SLA	0.588 to 0.784 N・m (6 to 8 kgf・cm)

- For tightening screws, if a tightening tool (such as a driver) hits the products, the package may crack, and internal stress fractures may occur, which shorten the lifetime of the electrical elements and can cause catastrophic failure. Tightening with an air driver makes a substantial impact. In addition, a screw torque higher than the set torque can be applied and the package may be damaged. Therefore, an electric driver is recommended.
  When the package is tightened at two or more places, first pre-tighten with a lower torque at all places, then tighten with the specified torque. When using a power driver, torque control is mandatory.

- Please pay special attention about the slack of the press mold. In case that the hole diameter of the heatsink is less

than 4 mm, it may cause the resin crack at tightening.

Soldering

- When soldering the products, please be sure to minimize the working time, within the following limits:
  - 260 ± 5 °C 10 ± 1 s (Flow, 2 times)
  - 380 ± 10 °C 3.5 ± 0.5 s (Soldering iron, 1 time)
- Soldering should be at a distance of at least 1.5 mm from the body of the products.

Electrostatic Discharge

- When handling the products, the operator must be grounded. Grounded wrist straps worn should have at least 1MΩ of resistance from the operator to ground to prevent shock hazard, and it should be placed near the operator.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in Sanken shipping containers or conductive containers, or be wrapped in aluminum foil.

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